

R-C Thermal Model Parameters

DESCRIPTION

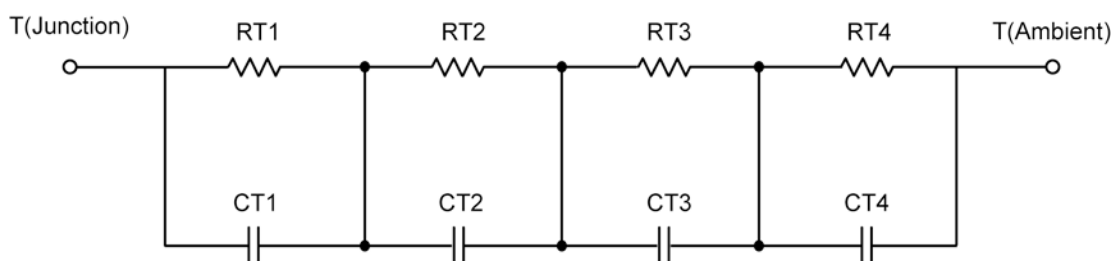
The parametric values in the R-C thermal model have been derived using curve-fitting techniques. These techniques are described in "[A Simple Method of Generating Thermal Models for a Power MOSFET](#)"[1]. When implemented in P-Spice, these values have matching characteristic curves to the Single Pulse Transient Thermal Impedance curves for the MOSFET.

R-C values for the electrical circuit in the Foster/Tank and Cauer/Filter configurations are included.

Note:

For a detailed explanation of implementing these values in P-SPICE, refer to [Application Note AN609 Thermal Simulations Of Power MOSFETs on P-SPICE Platform](#).

R-C THERMAL MODEL FOR TANK CONFIGURATION



| R-C VALUES FOR TANK CONFIGURATION | | | |
|--|------------|------|------------|
| Thermal Resistance (°C/W) | | | |
| Junction to | Ambient | Case | Foot |
| RT1 | 27.3321 | N/A | 5.9888 |
| RT2 | 33.7861 | N/A | 22.2008 |
| RT3 | 5.1992 | N/A | 4.8192 |
| RT4 | 58.6826 | N/A | 11.9912 |
| Thermal Capacitance (Joules/°C) | | | |
| Junction to | Ambient | Case | Foot |
| CT1 | 1.5578 m | N/A | 275.9981 m |
| CT2 | 15.5673 m | N/A | 3.0278 m |
| CT3 | 134.3328 u | N/A | 157.2160 u |
| CT4 | 1.2909 | N/A | 1.2711 m |

This document is intended as a SPICE modeling guideline and does not constitute a commercial product data sheet. Designers should refer to the appropriate data sheet of the same number for guaranteed specification limits.

R-C THERMAL MODEL FOR FILTER CONFIGURATION**R-C VALUES FOR FILTER CONFIGURATION**

| Thermal Resistance ($^{\circ}\text{C}/\text{W}$) | | | |
|--|------------|------|------------|
| Junction to | Ambient | Case | Foot |
| RF1 | 7.6775 | N/A | 9.2904 |
| RF2 | 34.3901 | N/A | 23.1352 |
| RF3 | 25.1235 | N/A | 7.6691 |
| RF4 | 57.8089 | N/A | 4.9053 |
| Thermal Capacitance (Joules/ $^{\circ}\text{C}$) | | | |
| Junction to | Ambient | Case | Foot |
| CF1 | 145.5501 u | N/A | 178.4103 u |
| CF2 | 1.6120 m | N/A | 1.1396 m |
| CF3 | 22.1179 m | N/A | 8.5941 m |
| CF4 | 1.2737 | N/A | 403.3337 m |

Note: NA indicates not applicable

Reference:

[1] "A Simple Method of Generating Thermal Models for a Power MOSFET" by Wharton McDaniel and Kandarp Pandya. IEEE / SEMITHERM 2002

